# TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS247A

## CD74AC253, CD54/74ACT253

August 1998 - Revised May 2000

## Features

- Buffered Inputs
- Typical Propagation Delay
  - 6.3ns at  $V_{CC}$  = 5V,  $T_A$  = 25<sup>o</sup>C,  $C_L$  = 50pF
- Exceeds 2kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-Resistant CMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
  - Fanout to 15 FAST™ ICs
  - Drives 50  $\Omega$  Transmission Lines

## **Dual 4-Input Multiplexer, Three-State**

### Description

The CD74AC253 and 'ACT253 dual 4-input multiplexers that utilize Advanced CMOS Logic technology. One of the four sources for each section is selected by the common Select inputs, S0 and S1. When the Output Enable ( $\overline{10E}$  or  $\overline{20E}$ ) is HIGH, the output is in the high-impedance state.

## **Ordering Information**

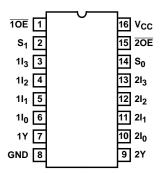
PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE
CD74AC253E	0 to 70 <sup>0</sup> C, -40 to 85, -55 to 125	16 Ld PDIP
CD74AC253M	0 to 70 <sup>0</sup> C, -40 to 85, -55 to 125	16 Ld SOIC
CD54ACT253F3A	-55 to 125	16 Ld CERDIP
CD74ACT253E	0 to 70 <sup>0</sup> C, -40 to 85, -55 to 125	16 Ld PDIP
CD74ACT253M	0 to 70 <sup>o</sup> C, -40 to 85, -55 to 125	16 Ld SOIC

NOTES:

- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Wafer and die for this part number is available which meets all electrical specifications. Please contact your local TI sales office or customer service for ordering information.

## Pinout

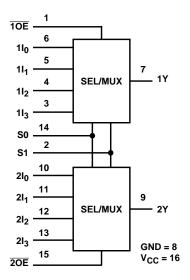




CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

 $\mathsf{FAST}^{\mathsf{TM}}$  is a Trademark of Fairchild Semiconductor.

## Functional Diagram



#### TRUTH TABLE

SELECT	INPUTS		DATA I	NPUTS		ENABLE INPUTS	OUTPUT
S1	S0	nl <sub>0</sub>	nl <sub>1</sub>	nl <sub>2</sub>	nl <sub>3</sub>	nOE	nY
Х	Х	Х	Х	Х	Х	Н	Z
L	L	L	Х	Х	Х	L	L
L	L	н	Х	Х	Х	L	Н
L	н	Х	L	Х	Х	L	L
L	Н	Х	н	Х	Х	L	Н
н	L	Х	Х	L	Х	L	L
н	L	Х	Х	н	Х	L	Н
н	н	Х	Х	Х	L	L	L
н	н	Х	Х	Х	н	L	Н

Select inputs S1 and S0 are common to both sections. H = High level, L = Low inputs, X = Don't care, Z = High impedance.

#### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub>
DC Input Diode Current, $I_{IK}$
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I <sub>OK</sub>
For V <sub>O</sub> < -0.5V or V <sub>O</sub> > V <sub>CC</sub> + 0.5V
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> (Note 3)±100mA
Operating Conditions

1 0
Temperature Range, T <sub>A</sub> 55°C to 125°C
Supply Voltage Range, V <sub>CC</sub> (Note 4)
AC Types
ACT Types4.5V to 5.5V
DC Input or Output Voltage, VI, VO 0V to VCC
Input Rise and Fall Slew Rate, dt/dv
AC Types, 1.5V to 3V 50ns (Max)
AC Types, 3.6V to 5.5V 20ns (Max)
ACT Types, 4.5V to 5.5V 10ns (Max)

### **Thermal Information**

Thermal Resistance (Typical, Note 5)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
PDIP Package	
SOIC Package	
Maximum lunction Temperature (Plactic Deckage)	1500

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTES:

3. For up to 4 outputs per device, add  $\pm 25$ mA for each additional output.

4. Unless otherwise specified, all voltages are referenced to ground.

5.  $\theta_{JA}$  is measured with the component mounted on an evaluation PC board in free air.

#### **DC Electrical Specifications**

		TE COND	v <sub>cc</sub>	25 <sup>0</sup> C		-40 <sup>o</sup> C TO 85 <sup>o</sup> C		-55 <sup>0</sup> C TO 125 <sup>0</sup> C			
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES											
High Level Input Voltage	VIH	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	evel Input Voltage V <sub>IL</sub> -	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	VOH	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

			ST ITIONS	v <sub>cc</sub>	25	25 <sup>0</sup> C		с то °С	-55°C TO 125 <sup>°</sup> C			
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN MAX		MIN	MAX	MIN	MAX	UNITS	
Low Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.05	1.5	-	0.1	-	0.1	-	0.1	V	
			0.05	3	-	0.1	-	0.1	-	0.1	V	
			0.05	4.5	-	0.1	-	0.1	-	0.1	V	
			12	3	-	0.36	-	0.44	-	0.5	V	
			24	4.5	-	0.36	-	0.44	-	0.5	V	
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V	
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V	
Input Leakage Current	I	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μΑ	
Three-State Leakage Current	I <sub>OZ</sub>	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND	-	5.5	-	±0.5	-	±5	-	±10	μΑ	
Quiescent Supply Current MSI	ICC	V <sub>CC</sub> or GND	0	5.5	-	8	-	80	-	160	μA	
ACT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	2	-	2	-	V	
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V	
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	4.5	4.4	-	4.4	-	4.4	-	V	
			-24	4.5	3.94	-	3.8	-	3.7	-	V	
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V	
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V	
Low Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.05	4.5	-	0.1	-	0.1	-	0.1	V	
			24	4.5	-	0.36	-	0.44	-	0.5	V	
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V	
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V	
Input Leakage Current	lj	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μA	
Three-State or Leakage Current	I <sub>OZ</sub>	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = V <sub>CC</sub> or GND	-	5.5	-	±0.5	-	±5	-	±10	μA	
Quiescent Supply Current MSI	Icc	V <sub>CC</sub> or GND	0	5.5	-	8	-	80	-	160	μA	
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	$\Delta I_{CC}$	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA	

NOTES:

6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

7. Test verifies a minimum 50  $\Omega$  transmission-line-drive capability at 85  $^{o}\text{C}$  , 75  $\Omega$  at 125  $^{o}\text{C}$  .

#### **ACT Input Load Table**

INPUT	UNIT LOAD						
S0, S1, nl <sub>0</sub> , nl <sub>1</sub>	1						
nOE	0.83						

NOTE: Unit load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

#### Switching Specifications Input t<sub>r</sub>, t<sub>f</sub> = 3ns, C<sub>L</sub> = 50pF (Worst Case)

			-40	°C TO 85°	с	-55			
PARAMETER	SYMBOL	v <sub>cc</sub> (v)	MIN	ТҮР	MAX	MIN	ТҮР	MAX	
AC TYPES				•					
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	227	-	-	250	ns
S0, S1, to Y		3.3 (Note 9)	7.2	-	25	7	-	28	ns
		5 (Note 10)	5.2	-	18.2	5	-	20	ns
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	151	-	-	166	ns
nl to Y		3.3	4.8	-	16.9	4.7	-	18.6	ns
		5	3.4	-	12.1	3.3	-	13.3	ns
Propagation Delay,	t <sub>PLZ</sub> , t <sub>PHZ</sub> ,	1.5	-	-	131	-	-	144	ns
Output Enable, Output Disable to Y	<sup>t</sup> PZL <sup>, t</sup> PZH	3.3	4.5	-	15.7	4.3	-	17.3	ns
		5	3	-	10.5	2.9	-	11.5	ns
Three-State Output Capacitance	CO	-	-	-	15	-	-	15	pF
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	107	-	-	107	-	pF
ACT TYPES		• •		•					
Propagation Delay, S0, S1, to Y	t <sub>PLH</sub> , t <sub>PHL</sub>	5 (Note 10)	5.7	-	20	5.5	-	22	ns
Propagation Delay, nl to Y	t <sub>PLH</sub> , t <sub>PHL</sub>	5	4.6	-	16.4	4.5	-	18	ns
Propagation Delay, Output Enable, Output Disable to Y	t <sub>PLZ</sub> , t <sub>PHZ</sub> , t <sub>PZL</sub> , t <sub>PZH</sub>	5	3.2	-	11.5	3.2	-	12.6	ns
Three-State Output Capacitance	CO	-	-	-	15	-	-	15	pF
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	107	-	-	107	-	pF

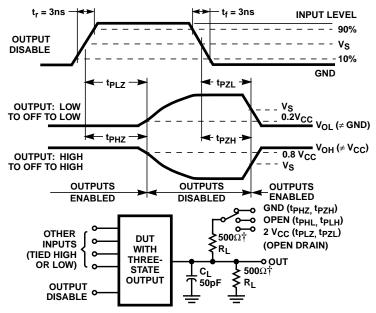
NOTES:

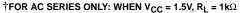
8. Limits tested 100%.

9. 3.3V Min is at 3.6V, Max is at 3V.

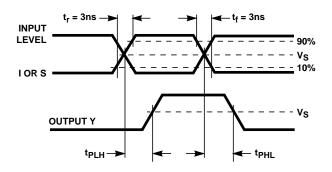
10. 5V Min is at 5.5V, Max is at 4.5V.

11.  $C_{PD}$  is used to determine the dynamic power consumption per multiplexer. AC:  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ ACT:  $P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC}$  where  $f_i$  = input frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.

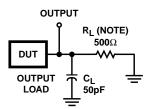




#### FIGURE 1. THREE-STATE PROPAGATION DELAY WAVEFORMS AND TEST CIRCUIT







NOTE: For AC Series Only: When  $V_{CC} = 1.5V$ ,  $R_L = 1k\Omega$ .

	AC	ACT
Input Level	V <sub>CC</sub>	3V
Input Switching Voltage, VS	0.5 V <sub>CC</sub>	1.5V
Output Switching Voltage, VS	0.5 V <sub>CC</sub>	0.5 V <sub>CC</sub>

FIGURE 3. PROPAGATION DELAY TIMES



### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	( )		-		-	()	(6)	(-)			
CD74AC253M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC253M	Samples
CD74ACT253E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT253E	Samples
CD74ACT253M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT253M	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC253M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74ACT253M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



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## PACKAGE MATERIALS INFORMATION

16-Apr-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74AC253M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74ACT253M96	SOIC	D	16	2500	340.5	336.1	32.0

## TEXAS INSTRUMENTS

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## TUBE



## - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD74ACT253E	N	PDIP	16	25	506	13.97	11230	4.32
CD74ACT253E	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

## D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



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